論文の内容の要旨

論文題目Development of Optical Methodology
for Extended-nano Fluidic Device Engineering
(拡張ナノ流体デバイス工学に向けた光学手法の開発)

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1. Introduction

Over the past decades, microfluidics has contributed various functional devices for analysis, synthesis, bio and related sciences and technologies. Recently, the downscaling of micro space to 10^{1} - 10^{2} nm space, which is referred to as extended-nano space, has opened new perspectives for integrated chemical systems. As the dimensions of channels decrease to extended-nano scale, unique fluidic and transport behaviors, which are negligible or absent in micro scale, play increasingly significant roles. For example, the liquid confined in 10^{1} - 10^{2} nm space was reported to have higher proton mobility, higher viscosity, and low dielectric constant, compared to those in bulk.^[1] Various novel analytical devices have also been developed to exploit new functionality. Especially, the 10^{1} nm space, whose scale is comparable to the characteristic length scales such as electric double layer (EDL), proton transfer layer, or the size of biomolecules promises many novel properties and devices, however the lack of fundamental methodology has limited the studies in this region of extended-nano fluidics.

Optical methodologies have been widely applied in detection, surface chemical modification, or fluidic control in microfluidics and extended-nano fluidics in 10^2 nm space. For example, the differential interference contrast thermal lens microscopy (DIC-TLM) is one of the ultra-sensitive optical detections applicable to nonfluorescent molecules in 10^2 nm space.^[2] However, the introduction of optical methodologies into 10^1 nm space is quite challenging, as the channel size is one order smaller than the wavelength of light, and the confocal length (~µm) that determines the detection area or the diffraction limit (~ 10^2 nm) that determines the spatial resolution of photochemical reactions. In such cases, conventional methods employing far-field light are not applicable. I focused on the optical near-field (ONF). ONF is generated on nanostructures whose sizes are much smaller than the wavelength. ONF can confine light in ~ 10^1 nm spaces and it has an apparent energy higher than the energy of incident photon.^[3] Therefore, the introduction of ONF into 10^1 nm space is expected to solve the problems of far-field light and bring new functionality. Here novel optical methodologies were developed for extended-nano fluidics in 10^1 nm space by device engineering and the integration of ONF. This doctoral thesis consists of three parts:

- (1) DIC-TLM detection in 10^1 nm space
- (2) ONF-assisted DIC-TLM detection of UV-absorbing biomolecules by visible light
- (3) ONF-assisted photochemical reactions for fabrication

2. DIC-TLM detection in 10¹ nm space

2. 1. New channel structure for compensation of signal cancellation in DIC-TLM detection

The principle of DIC-TLM detection is based on the change of temperature (d*T*), as the target molecules absorbs the excitation light, following by the change of refractive index (d*n*) in the medium. Signals are detected as the phase shift of light due to the change of refractive index, thus they are very sensitive to thermo-optical coefficient dn/dT of materials. When the channel size becomes 10^1 nm scale, most of generated thermal diffuses to the substrates. In conventional fluidic devices, SiO₂ is usually used as

substrate material. The dn/dT of SiO_2 is positive (dn/dT = +9.8) $\times 10^{-6}$ K⁻¹), while those of value solvents are negative. in Consequently, the signal induced solvents by is cancelled out by that of SiO₂ (figure 1(a)). Here, I proposed the compensation of cancellation by a new channel

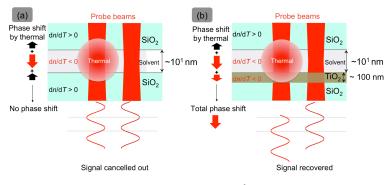


Figure. 1. (a) Signal cancellation in 10^{1} nm SiO₂-channel and (b) TiO₂-channel structure for compensating of signal cancellation

structure using negative dn/dT material - TiO₂ ($dn/dT = -3.0 \sim 1.8 \times 10^{-4} \text{ K}^{-1}$), as shown in figure 1(b). The phase shift induced in the lower TiO₂ substrate will compensate the phase shift in the upper SiO₂ substrate, consequently the signals are recovered. The required thickness of TiO₂ was determined to be 100 nm according to the calculation of thermal diffusion length in TiO₂ material.

2. 2. Verification of compensation of cancellation and DIC-TLM detection in 10^1 nm channel

The microchip using TiO₂ was successfully fabricated. The DIC-TLM measurements in TiO₂-channels with various channel depth *d* ranging in 10^1 – 10^2 nm were investigated, using Sunset Yellow dye as analyte and ethanol as solvent. The result in figure 2(a) clearly shows that sensitivity in SiO₂

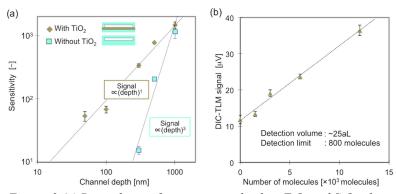


Figure. 2 (a) Dependency of sensitivity on depth in TiO_2 and SiO_2 -channel and (b) Calibration curve of dye in TiO_2 -channel (depth = 50nm)

channel was proportional to $(depth)^3$, while in TiO₂ channel, it was proportional to $(depth)^1$. It indicated that the signal cancellation was successfully compensated in TiO₂-channel, because without cancellation, the sensitivity should be proportional to $(depth)^1$ or the detection volume. The DIC-TLM detection was also successfully demonstrated in 50 nm-deep TiO₂-channel. The limit of detection (LOD) reached to zeptomole in a detection volume of 25 aL (figure 2(b)).

3. ONF-assisted DIC-TLM detection of UV-absorbing biomolecules by visible light

3.1 Principle of ONF-assisted DIC-TLM

In ONF-assisted DIC-TLM, the nanostructures were fabricated in 10^1 nm channel (nano-in-nano structures) by top-down nanofabrication for the ONF generation. As visible light was irradiated, the ONF was generated as an integrated light source (figure 3). The ONF with apparent higher energy photon allowed the absorption of UV-absorbing analyte molecules,

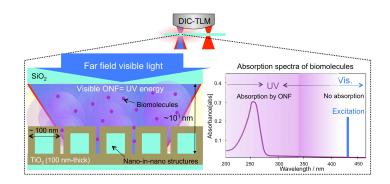
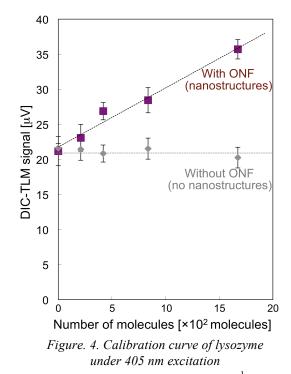


Figure 3. Principle of ONF-assisted DIC-TLM detection of UV-absorbing biomolecules by visible light in 10^{1} nm space

even though the energy of incident photon was lower than the absorption energy of analyte. The light absorption was then sensitively detected by DIC-TLM. Here, the channel consisted of TiO_2 -nanostructures on the lower substrate, and the upper substrate of SiO_2 , was used for DIC-TLM detection in 10^1 nm space (using the result of chapter 2).

3. 2 Principle verification and detection of UV-absorbing protein by visible light

The proposed ONF-assisted DIC-TLM principle was verified using channels with nanostructures (for example, width (213 \pm 16) nm × gap (69 \pm 9) nm × height (50±2) nm) integrated. Target protein (lysozyme) in phosphate buffer solution was used as analyte, and 405 nm visible light (intensity: 4mW) was used as the excitation beam. Although lysozyme has absorption band at ~240 nm and no absorption at 405 nm light, the calibration curve in figure 4 clearly showed that signals derived from lysozyme were detected in channel with nanostructures integrated, while in flat channel (without nanostructures), no signals derived from analyte were detected. The dependency of signals on excitation intensity showed that signal was proportional to (intensity)¹, which excluded the possibility of signal induced from the non-linear two

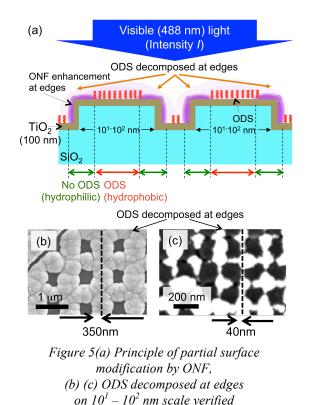


photon absorption. The principle was verified. The detection of UV-absorbing biomolecules in 10^{1} nm space with visible excitation was successfully realized by the assistance of ONF. Even under the low excitation intensity of 4 mW, the detection limit of ~220 molecules, which was three orders lower than conventional non-label detection methods in micro/nanofluidics, was achieved.

4. ONF-assisted photochemical reactions for fabrication

4. 1 Partial surface modification by ONF

Photochemical surface modification is an important technique in functionalization of devices such as patterning of biomolecules for molecular capture, hydrophobic/hydrophilic patterning for fluidic control, etc. However, in 10¹ nm space, as the channel size is much smaller than the wavelength, the conventional far-field techniques are not applicable due to the diffraction limit of light. Here, new partial surface modification on 10¹ nm scale by ONF was proposed, as described in figure 5(a). As TiO₂ nanostructures were irradiated with visible (488 nm) light, ONF was generated and enhanced at the edges of nanostructures. This ONF allows the excitation of TiO₂, leading to the photocatalytic decomposition of modifying chemicals (e.g. hydrophobic octadecylsilane (ODS)) at the edges of



nanostructures, even though the light energy (visible) is lower than the bandgap of TiO₂ (~380 nm). As a result, pattern sizes on scale of ONF ($\sim 10^1$ nm) can be achieved. SEM images in figure 5(b), (c) verified the ODS decomposition at the edges or nanostructures, while the centers remained untreated. At minimum, 40 nm ODS-decomposed (hydrophillic) patterns were achieved (figure 5(c)). Importantly, the pattern size could be easily controlled on $10^1 - 10^2$ nm scale by irradiation intensity.

4. 2 Visible response photocatalytic water splitting by ONF

The ONF-assisted photochemical reaction was also applied to the photocatalytic water splitting by visible light. The result showed a two orders enhancement in visible response of water splitting in nanostructures TiO₂ compared to TiO₂ flat film without nanostructure.^[4] The reaction is promising for fuel (hydrogen) generation in integrated energy devices.

5. Conclusion

In summary, novel optical methodologies such as DIC-TLM detection, surface modification, etc. were successfully introduced to extended-nano fluidics in 10^1 nm space by device engineering and the integration of ONF. This study has contributed fundamental tools that may accelerate the studies on fluidic behavior, or properties of liquid confined in 10^1 nm space, and the development of functional devices employing those unique properties. The combination of nanophotonics and extended-nano fluidics also promises many novel spectroscopies in extremely small spaces.

6. References

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